

Notice of References Cited

Application/Control No.

09/712,190

Applicant(s)/Patent Under
Reexamination
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Examiner
HOAN C. NGUYEN

Art Unit
2871

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification	
	A	US-5994721-A	10-1999	ZHONG ET AL.	257	89
	B	US-6104510-A	12-2000	KASHIWAZAKI ET AL.	427	511
	C	US-6104459-A	08-2000	OIKE ET AL.	349	105
	D	US-5724107-A	03-1998	NISHIKAWA ET AL.	349	38
	E	US-6211928-B1	04-2001	OH ET AL.	349	43
	F	US- -				
	G	US- -				
	H	US- -				
	I	US- -				
	J	US- -				
	K	US- -				
	L	US- -				
	M	US- -				

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification	
	N	- -					
	O	- -					
	P	- -					
	Q	- -					
	R	- -					
	S	- -					
	T	- -					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)				
	U	Pichon et al.; "Low temperature unhydrogennated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Volume 296, pages 133-136 (1997)				
	V					
	W					
	X					

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.